

STXL Series Microchip Lasers



1. STXL Series Sub-Nanosecond Microchip Lasers

The STXL series microchip lasers are passively Q-switched diode-pumped sub-nanosecond lasers, featuring narrow pulse width, high peak power high repetition rate and multiple wavelengths. We provide these microchip lasers at 1535nm, 1319nm, 1064nm, 1030nm, 946nm, 660nm, 532nm, 515nm, 473nm, 355nm, 343nm, 266nm, 257nm, 237nm and 213nm output wavelengths, with repetition rates up to 100kHz and pulse width from 300ps to 5ns. These compact and easy-to-integrate diode-pumped solid-state lasers support internal and external triggering, are ideally suited for eye-safe ranging, atmospheric monitoring, underwater imaging, optical metrology, bio-medicine, micro-machining etc.

1.1 STXL-AR Series 1.5ns Microchip Lasers

STXL-AR series microchip lasers are passively Q-switched diode-pumped solid-state lasers. The integrated design of diode-pumped module and laser crystal brings convenience to installation and integration due to the compact size. This series of lasers offer miniaturized drive boards specially for meteorological radar application, featuring small size, low power consumption, and can be used in high altitude, large temperature difference and other harsh environment.

Applications:

- LIDAR
- Laser ranging
- Atmospheric monitoring

- Pulse width down to 1.5ns
- Single pulse energy up to 200µJ
- Repetition rate up to 2.5kHz
- Spatial mode TEM00
- Sealed package, high reliability



Wavelength(nm)	10	1064 532					
Repetition rate (kHz)		2.5*					
Average power (mW)	300	300 500 150					
Pulse energy (µJ)	110	110 180		90			
Pulse width (ps)	20	2000 1500					
Power stability (8h)		±3%					
Beam profile		TEI	M00				



Beam full divergence (typ., mrad)	Horizontal @1/e²	≤3 ≤		≤2	≤2.5				
	Vertical @1/e ²	≤3 ≤2.5							
Polarization ratio			>10	00:1					
Supply power voltage		100-240V <i>A</i>	C, 50/60Hz						
Control interface	Control interface			RS232, USB					
Power consumption (W)		≤20	≤25	≤25	≤25				
Power dimensions (W×H×L, m	nm)	90×32.6×120							
Laser head dimensions (W×H	×L, mm)	45×30×120							
Operation temperature (°C)	15-35								
Storage temperature (°C)	0-60								

^{*} Side-exit light structure. Trigger mode for frequency <20kHz is rising-edge trigger, trigger mode for frequency >20kHz is gated trigger, TTL 5V, SMA interface.

1.2 STXL-A Series Microchip Lasers

STXL-A series microchip lasers are compact, economical and reliable diode-pumped passive Q-switch solid-state lasers, with stable output energy, high peak powers and excellent beam quality. The monolithic laser cavity is permanently aligned, therefore extremely stable. The system supports internal trigger and external trigger.

Applications:

- Seed laser
- Micromachining
- Pump source for optical parametric oscillators
- Laser-induced breakdown spectroscopy (LIBS)
- Laser-based ultrasound detection
- Laser ionization mass spectroscopy (LIMS)
- Laser ranging
- Laser-induced fluorescence (LIF)
- Laser ultrasonic imaging

- Single pulse energy up to 120μJ
- Repetition rate up to 10kHz
- Spatial mode TEM00
- Polarization-stable



Wavelength (nm)			1064			532			355			266	
Repetition rate (k	Hz)	1	5	10	1	5	10	1*	5*	10*	1*	5*	10*
Average power (r	nW)	120	350	400	60	150	150	30	50	50	10	40	30
Pulse energy (µJ)		120	120 70 30			35	15	15	10	6	8	7	3
Pulse width (ps)		2000 1500 1			1500	20	00	1500	12	200	1500	12	00
Power stability (8	h)	±3%											
Beam profile		TEM00											
Beam full divergence	Horizontal @1/e²	8				6		5			5		
(typ., mrad)	Vertical @1/e ²		8 6			5			5				
Polarization ratio							>10	0:1					
Supply power vol	tage					10	0-240 VA	C, 50/60	Hz				
Control interface							RS232	2, USB					
Power consumpti	on (W)						≤;	35					
Power dimension	s (W×H×L, mm)						168×8	8×140					
Laser head dimer mm)	nsions (W×H×L,	45×30×120											
Operation temper	rature (°C)	15-35											
Storage temperat	ure (°C)						0-	60					



1.3 STXL-C Series 750ps Microchip Lasers

STXL-C series microchip lasers are compact, economical and reliable semiconductor pumped (diode pumped) passive Q-switch (passively Q-switched) solid state lasers independently developed by us, with stable output energy, high peak powers and excellent beam quality. The monolithic laser cavity is permanently aligned, therefore extremely stable. The system supports internal trigger and external trigger. This series of products include 5 wavelengths of 1064nm, 532nm, 355nm, 266nm and 213nm. The pulse duration (pulse width) can go down to 600ps (0.6ns). Various models operate with repetition rates up to 10kHz and the average power ranges from 3mW to 350mW. The reliable and robust microchip design is perfect for advanced OEM industrial applications.

Applications:

- Seed laser
- Micromachining
- Pump source for optical parametric oscillators
- Laser-induced breakdown spectroscopy (LIBS)
- Laser-based ultrasound detection
- Laser ionization mass spectroscopy (LIMS)
- Laser ranging
- Laser-induced fluorescence (LIF)
- Laser ultrasonic imaging

- Single pulse energy up to 120µJ
- Repetition rate up to 10kHz
- Spatial mode TEM00
- Polarization-stable



Wavelength (nm))		1064			532			355			266		213
Repetition rate (F	(Hz)	1	1 5 10			5	10	1*	5*	10*	1*	5*	10*	1*
Average power (mW)	100	100 300 300 50			150	150	20	50	50	10	40	40	4
Pulse energy (µJ	1)	120	70	30	60	35	15	15	10	6	8	7	3	4
Pulse width (ps)			750			750			650		650			650
Power stability (8	Bh)	±3%												
Beam profile		TEM00												
Beam full divergence	Horizontal @1/e ²	8	1:	2	7	1	0	5		8	5	1	3	5
(typ., mrad)	Vertical @1/e²	8	1:	2	7	1	0	5		8	5	;	3	5
Polarization ratio)							>100:1						
Supply power vo	Itage						100-24	10 VAC, 5	60/60 Hz					
Control interface							F	RS232, US	SB					
Power consumpt	tion (W)	≤	≤	≤	≤	≤	≤	≤	≤	≤	≤	≤	≤	≥
		25	20	30	25	30	35	25	25	30	25	30	30	25
Power dimension							1	68×88×1	40					
Laser head dime mm)	nsions (W×H×L,	45×30×120												
Operation tempe	rature (°C)	15-35												
Storage tempera	ture (°C)							0-60						·

^{*} Side-exit light structure. Trigger mode for frequency <20kHz is rising-edge trigger, trigger mode for frequency >20kHz is gated trigger, TTL 5V, SMA interface.



1.4 STXL-D Series 300ps-2ns Low Repetition Rate OEM Microchip Lasers

STXL-D series microchip lasers are passively Q-switched diode-pumped solid-state lasers, featuring stable single pulse energy, excellent beam quality and no tail pulse. 300ps-2ns low-repetition-rate microchip lasers coming along with miniaturized OEM drive boards, are designed especially for medical aesthetics. These lasers are compact, easy-to-integrate, and offer outstanding long working time. We also provide isolators with corresponding wavelengths and HQF series high-energy laser products for customers.

Applications:

Seed laser

Key Features:

- Pulse width down to 300ps
- Single pulse energy up to 50µJ
- Spatial mode TEM00
- Polarization-stable



Wavelength(nm)		1064					
Repetition rate (kHz) 0.01							
Average power (mW) 3							
Pulse energy (µJ)			3	00			
Pulse width (ps)		500	350	500	2000		
Power stability (8h) ±3%							
Beam profile			TEI	M00			
Beam full divergence	Horizontal @1/e ²	6	6	4-6	4-6		
(typ., mrad)	Vertical @1/e ²	6	6	4-6	4-6		
Polarization ratio		P-polarized, >100:1 500ps: P-polarized, >10					
		2ns: S-polarized, >100:1					
Supply power voltage		12V 2A					
Control interface		SMA					
Power consumption (W)		≤	10			
Power dimensions (W×	H×L, mm)	68×3	5×120	100x2	3x100		
Laser head dimensions (W×H×L, mm)		45×30×120 145x70x46					
Operation temperature (°C)		15-35					
Storage temperature (°0	<u> </u>	0-60					

1.5 STXL-D Series 350ps Microchip Lasers

STXL-D series microchip lasers are passively Q-switched diode-pumped solid-state lasers, featuring stable single pulse energy, excellent beam quality and no tail pulse. The integrated design of diode-pumped module and laser crystal brings convenience to installation and integration due to the compact size. This series provides various wavelengths include 1064nm, 532nm, 355nm and 266nm, and supports internal and external triggering. The internal hermetic module of the laser head is available to customers for tailor-made development. The STXL-D series is also available with OEM seed laser drivers.

Applications:

- Seed laser
- Micromachining
- Laser-induced breakdown spectroscopy (LIBS)
- Laser ionization mass spectroscopy (LIMS)
- Laser-induced fluorescence (LIF)
- Nonlinear optics

- Pulse width down to 300ps
- Single pulse energy up to 50µJ
- Repetition rate up to 10kHz





- Spatial mode TEM00
- Polarization-stable

Wavelength (nm)		1064 532 355 266						
Repetition rate (kHz)		0.1	0.1	0.1	0.1			
Average power (mW)		10 3 1.5 0.5						
Pulse energy (µJ)		100	30	15	5			
Pulse width (ps)		350	300	300	300			
Power stability (8h)		±3%						
Beam profile TEM00								
Beam full divergence typ., mrad)	Horizontal @1/e²	12	10	8	8			
	Vertical @1/e²	12	10	8	8			
Polarization ratio		>100:1						
Supply power voltage			100-240 V	AC, 50/60 Hz				
Control interface			RS23	2, USB				
Power consumption (V	V)		≤	25				
Power dimensions (W	×H×L, mm)		168×8	38×140				
Laser dimensions (W×H×L, mm) 45×30×120								
Operation temperature (°C) 15-35								
Storage temperature (°C)		0.	-60				

1.6. STXL-H Series 300ps Single Longitudinal Mode Microchip Lasers

STXL-H series single longitudinal mode (SLM) microchip lasers are compact, economical and reliable semiconductor pumped (diode pumped) passive Q-switch (passively Q-switched) solid state lasers with stable output energy, high peak power and excellent beam quality. The monolithic laser cavity is permanently aligned, therefore extremely stable. The system supports internal trigger and external trigger. This series of products produce the single longitudinal mode 1064nm, 532nm, 355nm, 266nm and 213nm radiation with a long lifetime. The pulse duration (pulse width) can go down to 300ps (0.3ns). Various models operate with repetition rates up to 50kHz and the average power ranges from 2mW to 100mW. The reliable and robust microchip design is perfect for advanced OEM industrial applications.

Applications:

- Seed laser
- Micromachining
- Raman spectroscopy
- Laser ranging
- Laser-induced fluorescence (LIF)
- Laser ultrasonic imaging
- Time of flight mass spectrometer (TOFMS)
- Photolithography

- Pulse width down to 300ps
- High energy stability
- Repetition rate up to 100kHz
- Spatial mode TEM00
- Polarization-stable



Wavelength (nm)	Wavelength (nm)		64	532		
Repetition rate (kHz)	Repetition rate (kHz)			20	100	
Average power (mW)	60	100	30	50		
Pulse energy (µJ)	3	1	1.5	0.5		
Pulse width (ps)	Pulse width (ps)			300	450	
Power stability (8h)		±3%				
Beam profile TEM00						
	Horizontal @1/e ²	25	30	16	25	



Beam full divergence	Vertical @1/e²	25	30	16	25			
(typ., mrad)								
Polarization ratio		>100:1						
Supply power voltage		100-240 VAC,50/60 Hz						
Control interface		RS232, USB						
Power consumption (W))	≤35	≤40	≤35	≤40			
Power dimensions (W×I	H×L, mm)		168×8	8×140				
Laser head dimensions	(W×H×L, mm)	45×30×120						
Operation temperature ((°C)	15-35						
Storage temperature (°C	<u>C)</u>	0-60						

1.7 STXL-I Series 2.5ns Microchip Lasers

STXL-I series microchip lasers are compact, economical and reliable semiconductor pumped (diode pumped) passive Q-switch (passively Q-switched) solid state lasers independently developed by us, with stable output energy, high peak powers and excellent beam quality. The monolithic laser cavity is permanently aligned, therefore extremely stable. The system supports internal trigger and external trigger.

Applications:

- Laser-induced fluorescence (LIF)
- Laser-based ultrasound detection
- Laser ranging
- Raman spectroscopy

- Compact design, excellent stability
- Polarization-stable
- Repetition rate up to 5kHz
- Spatial mode TEM00



Wavelength (nm)		946	473				
Repetition rate (kHz)	epetition rate (kHz)		1				
Average power (mW)		20	5				
Pulse energy (µJ)		20	5				
Pulse width (ps)		2500	2000				
Power stability (8h)		±3	3%				
Beam profile		TEN	M00				
Beam full divergence	Horizontal @1/e ²	9	7				
(typ., mrad)	Vertical @1/e ²	9	7				
Polarization ratio		>100:1					
Supply power voltage		100-240 VA	100-240 VAC, 50/60 Hz				
Control interface		RS232	2, USB				
Power consumption (W)		≤15	≤15				
Power dimensions (W×I	H×L, mm)	168×8	8×140				
Laser head dimensions	(W×H×L, mm)	45×30)×120				
Operation temperature (Operation temperature (°C)		15-35				
Storage temperature (°C	2)	0-60					



1.8 STXL-J Series 1ns Microchip Lasers

Applications:

- Material micromachining
- Spectrum analysis
- LIDAR
- Pump source
- Biomedicine

Key Features:

- Pulse width down to 1ns
- Single pulse energy up to 100μJ
- Repetition rate up to 2kHz
- Spatial mode TEM00



Wavelength (nm)		1030	515	343	257
Repetition rate (kHz)	1	1	1*	1*	
Average power (mW)		100	40	20	8
Pulse energy (µJ)		100	40	20	8
Pulse width (ps)		1000	900	800	800
Power stability (8h)			±3	3%	
Beam profile			TEN	M00	
Beam full divergence	Horizontal @1/e ²	6	4	3	2
(typ., mrad)	Vertical @1/e ²	6	4	3	2
Polarization ratio			>10	00:1	
Supply power voltage			100-240 VA	C, 50/60 Hz	
Control interface			RS232	2, USB	
Power consumption (W)		≤15	≤15	≤15	≤15
Power dimensions (W×I	H×L, mm)	168×88×140			
Laser head dimensions	(W×H×L, mm)	45×30×120			
Operation temperature ((°C)	15-35			_
Storage temperature (°C	<u> </u>		0-	60	

1.9 STXL-O Series Energy Adjustable Fiber Pigtailed Microchip Lasers

STXL-O series sub-nanosecond fiber pigtailed microchip lasers are composed of integrated electronic control modules for energy adjustment, photodetector module and laser drive board, with a 200um 0.22NA fiber. This super compact laser is plug and play, making it an ideal source for a variety of applications.

Applications:

- Laser engraving
- Laser-induced breakdown
- spectroscopy (LIBS)
- Laser photoluminescence
- Laser marking
- Laser capture microdissection
- Laser-induced fluorescence (LIF)
- Laser mass spectroscopy
- Ultraviolet microscopy
- Raman spectroscopy
- LIDAR
- Thin film scribing and processing
- Semiconductor inspection
- Photoacoustic imaging
- Laser spark plug
- Laser remote sensing





- Pulse width <1ns
- Repetition rate variable from 1-200Hz
- Energy adjustable by PC control
- Photodiode output signal with time jitter < 00ps
- Sealed package, high reliability
- Plug and play, include PC control software

Wavelength (nm)	1064 532 355 266					
Repetition rate (Hz)		1-2	200			
Max. energy @ Fiber coupled output (μJ)	50	25	25	10		
Pulse width (ns)		≤	<u> </u>			
Energy stability (RMS)		≤(3%			
Adjusting precision of output energy		≤2	2%			
Polarization		≥1(00:1			
Fiber	200µm/0.22NA					
Supply power voltage		24\	/ DC			
Modulation input		TTL 0-5V,	SMB input			
Control interface		RS-	-232			
Peak Power consumption (W)		<	20			
Average power consumption (W)		<	10			
Laser dimensions (W×H×L, mm)		82x7	9x250			
Operation temperature (°C)		15	-35			
Storage temperature (°C)		-10)-60			

1.10 STXL-O Series Energy Adjustable Free Space Microchip Lasers

STXL-O series energy adjustable sub-nanosecond microchip lasers with free space output, are composed of integrated electronic control modules for energy adjustment, photodetector module and laser drive board. This laser features compact design, plug and play, and free space output with a beam divergence lower than 2mrad.

Applications:

- Laser engraving
- Laser-induced breakdown
- spectroscopy (LIBS)
- Laser photoluminescence
- Laser marking
- Laser capture microdissection
- Laser-induced fluorescence (LIF)
- Laser mass spectroscopy
- Ultraviolet microscopy
- Raman spectroscopy
- LIDAR
- Thin film scribing and processing
- Semiconductor inspection
- Photoacoustic imaging
- Laser spark plug
- Laser remote sensing

- Pulse width <1ns
- Repetition rate variable from 1-200Hz
- Energy adjustable by PC control
- Photodiode output signal with time jitter <100ps
- Sealed package, high reliability
- Plug and play, include PC control software





Wavelength (nm)		1064 532 355						
Repetition rate (Hz)		1-200		-200				
Max. energy @ free space	e output (μJ)	60	30	25	15			
Pulse width (ns)		·		≤1				
Energy stability (RMS)			:	≤3%				
Adjusting precision of out	put energy			≤2%				
Beam profile (Free space	output)		TI	EM00				
Full angle divergence	Horizontal @1/e ²	≤2						
Typ. (mrad)	Vertical @1/e ²	≤2						
Polarization		≥100:1						
Supply power voltage		24V DC						
Modulation input			TTL 0-5\	/, SMB input				
Control interface			R	S-232				
Peak power consumption	(W)	<20						
Average power consumpt	tion (W)	<10						
Laser dimensions (W×H×	L, mm)		82x′	103x240				
Operation temperature (°	peration temperature (°C)		15-35					
Storage temperature (°C)				0-60				

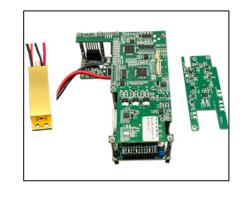
1.11 STXL-M Series Microchip Lasers

STXL-M series microchip lasers are passively Q-switched diode-pumped solid-state lasers, featuring high energy, good value and low power consumption. The integrated design of diode-pumped module and laser crystal results in the compactness. And water cooling is not required for this laser. The series is also available with miniaturized drive boards for OEM control or PD signal for applications include LIBS and laser ablation, which is easy to install and integrate, and is suitable for handheld devices.

Applications:

- Laser ablation
- Laser-induced breakdown
- spectroscopy (LIBS)

- Pulse width <7ns
- Pulse energy up to 20mJ
- Built-in PD, drive board for PD available
- Compact size, no water cooing required
- Suitable for handheld devices
- Cost effective



Wavelength (nm)		1064
Repetition rate (Hz)		10
Pulse energy (mJ)		>10
Pulse width (ns)		<3
Power stability (RMS)		<3%
Full angle divergence	Horizontal @1/e ²	3
Typ. (mrad)	Vertical @1/e ²	3
Cooling method		Air cooling
		17×16.1×58.5 (customizable)
Operation temperature (°C		15-35
Storage temperature (°C)	temperature (°C) -20 - +60	
Supply power voltage		12VDC
Control interface		RS-232 or I/O
Power consumption (W)		15W (MAX)
*Drive board dimensions (*Drive board dimensions (W×H×L, mm) 45×40×111	
Trigger mode	·	External or Internal Trigger
Drive board dimensions (V	V×H×L, mm)	39×10×86(customizable)



2. STXL Series 1535nm Er:glass Lasers

2.1 STXL High Repetition Rate 1535nm Microchip Laser Module

Er:glass eye-safe lasers are diode pumped, water-free, passively Q-switched lasers independently developed by us, combine eye-safe wavelength operation with high peak power, short pulse duration (pulse width), and diffraction limited beam quality to deliver unmatched size, weight and power. Our eye-safe DPSS lasers operate at 1535nm, in addition to being called 1535nm lasers, these lasers are also called 1540nm lasers, 1534nm lasers, 1.54um lasers or 1.54µm lasers, widely used as the emission light source of rangefinder. At this wavelength, eye-safe laser ranging systems can be easily configured without compromise to beam power or quality. This makes laser ranging applications safer for customers. Most of these lasers are operational over a wide temperature range from -40°C to 60°C, with lifetime exceeding 60 million shots.

Applications:

- Obstacle avoidance radar
- Meteorological radar
- Laser range finder

Key Features:

- Passively Q-switched, Er:glass
- Eye-safe
- Extremely light (about 10g)
- Wide operating temperature range



Wavelength (nm)		15	35	
Pulse energy (μJ)	40	20	10	5
Repetition rate (kHz)	1	2.5	5	10
Pulse width (ns)	≤5	≤6	≤8	≤10
Operating current (A)			5	
Operating voltage (V)			2	
Beam diameter (mm)		0	.3	
Beam full divergence (typ., mrad)	≤16	≤17	≤18	≤20
Beam pointing		< 0	.2°	
Beam profile		TEN	M00	
Weight (g)		≤′	10	
Dimensions (W×H×L, mm)		21x	8x7	
Operation temperature (°C)	-40~65			
Storage temperature (°C)		-55	~80	

Part numbering:

Series - Wavelength - Pulse Energy - Pulse Repetition Rate - HRR-Q

For example: STXL-1535nm-40uJ-1kHz-HRR-Q, is a STXL series high repetition rate passively Q-switched microchip laser with 1535nm wavelength, 40uJ energy, 1kHz pulse repetition rate.

2.2 STXL 100~300µJ 1535nm Microchip Laser Modules

Er:glass eye-safe lasers are diode pumped, water-free, passively Q-switched lasers combined eye-safe wavelength operation with high peak power, short pulse duration (pulse width), and diffraction limited beam quality to deliver unmatched size, weight and power. Our eye-safe DPSS lasers operate at 1535nm, in addition to being called 1535nm lasers, these lasers are also called 1540nm lasers, 1534nm lasers, 1.54um lasers or 1.54µm lasers, widely used as the emission light source of rangefinder. At this wavelength, eye-safe laser ranging systems can be easily configured without compromise to beam power or quality. This makes laser ranging applications safer for customers. Most of these lasers are operational over a wide temperature range from -40°C to 60°C, with lifetime exceeding 60 million shots.



Applications:

- Laser range finder
- Meteorological radar

Key Features:

- Passively Q-switched, Er:glass
- Eye-safe
- Extremely light
- Super compact design
- Wide operating temperature range



Wavelength (nm)		1535	
Pulse energy (μJ)	100	200	300
Pulse width (ns)		≤5	
Repetition rate (Hz)		10	
Operating current (A)	7	10	12
Beam full divergence (typ., mrad)	10		
Beam profile		TEM00	
Weight (g)	7	10	12
Dimensions (W×H×L, mm)	21x8x7 25x8x7		
Operation temperature (°C)	-40~65		
Storage temperature (°C)		-55~80	

Part numbering:

Series - Wavelength - Pulse Energy - Pulse Repetition Rate - HRR-Q

For example: STXL-1535nm-100uJ-10Hz-HRR-Q, is a STXL series high repetition rate passively Q-switched microchip laser with 1535nm wavelength, 100uJ energy, 10Hz pulse repetition rate.

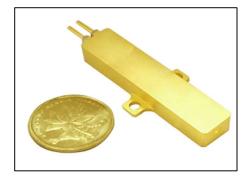
2.3 STXL High Energy 1535nm Microchip Laser Modules

Er:glass eye-safe lasers are diode pumped, water-free, passively Q-switched lasers combined eye-safe wavelength operation with high peak power, short pulse duration (pulse width), and diffraction limited beam quality to deliver unmatched size, weight and power. Our eye-safe DPSS lasers operate at 1535nm, in addition to being called 1535nm lasers, these lasers are also called 1540nm lasers, 1534nm lasers, 1.54um lasers or 1.54µm lasers, widely used as the emission light source of rangefinder. At this wavelength, eye-safe laser ranging systems can be easily configured without compromise to beam power or quality. This makes laser ranging applications safer for customers. Most of these lasers are operational over a wide temperature range from -40°C to 60°C, with lifetime exceeding 60 million shots.

Applications:

- Laser range finder
- Altimeter
- LIBS

- Peak power >150kW
- Eye-safe
- No temperature controlling
- Low operating current
- Compact size



Wavelength (nm)	15	535	
Pulse energy (μJ)	800	1000	
Pulse width (ns)	≤7	≤8	
Repetition rate (Hz)	10	5	
Operating current (A)	3	30	
Beam full divergence (typ., mrad)	≤	≦ 7	
Beam profile	TE	M00	



Weight (g)	20
Dimensions (W×H×L, mm)	38x9x7.7
Operation temperature (°C)	-40~65
Storage temperature (°C)	-55~80

Part numbering:

Series - Wavelength - Pulse Energy - Pulse Repetition Rate - HE

For example: STXL-1535nm-800uJ-10Hz-HE, is a STXL series high energy microchip laser with 1535nm wavelength, 800uJ energy, 10Hz pulse repetition rate.

2.4 STXL 500µJ High Energy 1535nm Microchip Laser Modules

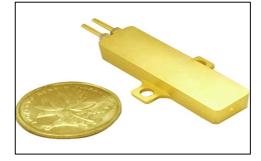
Er:glass eye-safe lasers are diode pumped, water-free, passively Q-switched lasers combined eye-safe wavelength operation with high peak power, short pulse duration (pulse width), and diffraction limited beam quality to deliver unmatched size, weight and power. Our Eye-safe DPSS Lasers operate at 1535nm, in addition to being called 1535nm lasers, these lasers are also called 1540nm lasers, 1534nm lasers, 1.54um lasers or 1.54µm lasers, widely used as the emission light source of rangefinder. At this wavelength, eye-safe laser ranging systems can be easily configured without compromise to beam power or quality. This makes laser ranging applications safer for customers. Most of these lasers are operational over a wide temperature range from -40°C to 60°C, with lifetime exceeding 60 million shots.

Applications:

- Laser range finder
- Meteorological radar

Key Features:

- Passively Q-switched, Er:glass
- Eye-safe
- Extremely light
- Super compact design
- Wide operating temperature range



Wavelength (nm)	1535
Pulse energy (μJ)	500
Pulse width (ns)	≤6
Repetition rate (Hz)	10
Operating current (A)	20
Beam full divergence (typ., mrad)	6
Beam profile	TEM00
Weight (g)	13
Dimensions (W×H×L, mm)	32x8x7
Operation temperature (°C)	-40~65
Storage temperature (°C)	-55~80

Part numbering:

Series – Wavelength – Pulse Energy – Pulse Repetition Rate – HE

For example: STXL-1535nm-500uJ-10Hz-HE, is a STXL series high energy microchip laser with 1535nm wavelength, 500uJ energy, 10Hz pulse repetition rate.



SLY Series 1535nm Erbium-Doped Glass Lasers



Features:

- Human eye safety
- Small size and light weight
- High photoelectric conversion efficiency
- Adapt to the harsh operating environment

Applications:

- Laser Ranging
- LIDAR
- Laser Communication

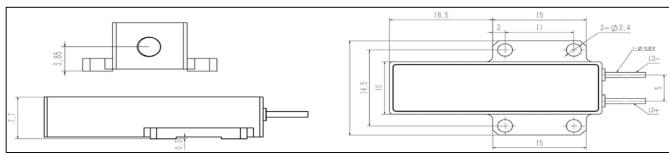
1. A1 Series Er Glass Lasers SLY-1535-xxx-A1



Parameters	SLY-1535-100-A1	SLY-1535-200-A1	SLY-1535-300-A1	SLY-1535-400-A1
Wavelength	1535nm			
Pulsed width (FWHM)		3ns	- 6ns	
Pulsed energy (µJ)	100	200	300	400
Peak Power (kw)	25	50	70	80
Energy Stability		≤!	5%	
Beam-divergence angle		≤12mrad		
Working Voltage		2V		
Working current (A)	7 12 12 14			
Working Frequency	1Hz – 10Hz			
Pulsed Width		1ms -2.5ms		
Working temperature		-40°C - 60°C		
Storage temperature	-50°C - 70°C			
Life Time	10000000 times			
Weight		<1	10g	

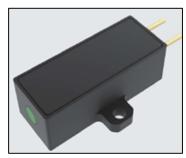


Dimension of SLY-1535-xxx-A1:



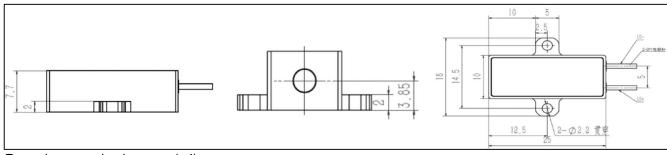
Remark: xxx: pulsed energy (µJ)

2. A3 Series Er Glass Lasers SLY-1535-xxx-A3



Parameters	SLY-1535-100-A3	SLY-1535-200-A3	SLY-1535-300-A3	SLY-1535-400-A3
Wavelength	1535nm			
Pulsed width (FWHM)		3ns	- 6ns	
Pulsed energy (µJ)	100	200	300	400
Peak Power (kw)	25	50	70	80
Energy Stability		≤5%		
Beam-divergence angle		≤12mrad		
Working Voltage		2V		
Working current (A)	7	12	12	14
Working Frequency	1Hz - 10Hz			
Pulsed Width		1ms - 2.5ms		
Working temperature		-40°C - 60°C		
Storage temperature		-50°C - 70°C		
Life Time	10000000 times			
Weight		<1	10g	

Dimension of SLY-1535-xxx-A3:



Remark: xxx: pulsed energy (µJ)

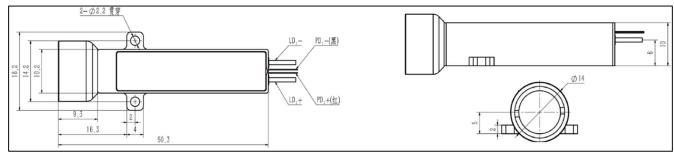
3. A4 Series Er Glass Lasers SLY-1535-xxx-A4





Parameters	SLY-1535-100-A4	SLY-1535-200-A4	SLY-1535-300-A4	SLY-1535-400-A4
Wavelength	1535nm			
Pulsed width (FWHM)		3ns	- 6ns	
Pulsed energy (µJ)	100	200	300	400
Peak Power (kw)	25	50	70	80
Energy Stability		≤5	5%	
Beam-divergence angle		≤0.5mrad		
Working Voltage		2V		
Working current (A)	7 12 12 14			
Working Frequency	1Hz - 10Hz			
Pulsed Width		1ms - 2.5ms		
Working temperature		-40°C - 60°C		
Storage temperature	-50°C - 70°C			
Life Time	10000000 times			
Weight		<2	20g	

Dimension of SLY-1535-xxx-A4:



Remark: xxx: pulsed energy (µJ)

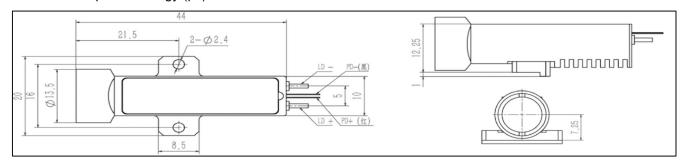
4. A5 Series Er Glass Lasers SLY-1535-xxx-A5





Parameters	SLY-1535-100-A5	SLY-1535-200-A5	SLY-1535-300-A5	SLY-1535-400-A5
Wavelength	1535nm			
Pulsed width (FWHM)		3ns	- 6ns	
Pulsed energy (µJ)	100	200	300	400
Peak Power (kw)	25	50	70	80
Energy Stability		≤!	5%	
Beam-divergence angle		≤0.5mrad		
Working Voltage		2V		
Working current (A)	7 12 12 14			
Working Frequency	1Hz - 10Hz			
Pulsed Width		1ms - 2.5ms		
Working temperature		-40°C - 60°C		
Storage temperature	-50°C - 70°C			
Life Time	10000000 times			
Weight		<2	20g	

Dimension of SLY-1535-xxx-A5: Remark: xxx: pulsed energy (µJ)



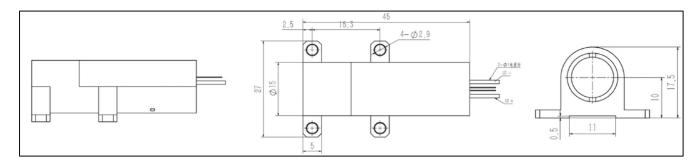
5. A6 Series Er Glass Lasers SLY-1535-40-A6



Parameters	SLY-1535-40-A6
Wavelength	1535nm
Pulsed width (FWHM)	3ns - 5ns
Pulsed energy (µJ)	40
Peak Power (kw)	10
Energy Stability	≤5%
Beam-divergence angle	≤0.5mrad
Working Voltage	2V
Working current (A)	3
Working Frequency	10000Hz
Pulsed Width	0.2ms - 0.4ms
Working temperature	-40°C - 60°C
Storage temperature	-50°C - 70°C
Life Time	10000000 times
Weight	<20g



Dimension of SLY-1535-40-A6:

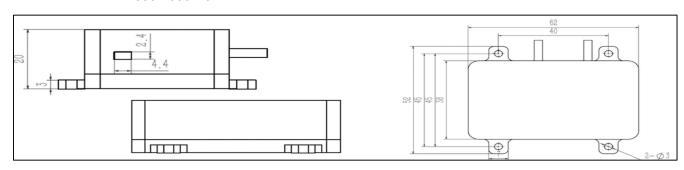


6. A8 Series Er Glass Lasers SLY-1535-2000-A8



Parameters	SLY-1535-2000-A8	
Wavelength	1535nm	
Pulsed width (FWHM)	10ns - 15ns	
Pulsed energy (µJ)	2000	
Peak Power (kw)	150	
Energy Stability	≤5%	
Beam-divergence angle	≤4mrad	
Working Voltage	<4V	
Working current (A)	70	
Working Frequency	1Hz – 5Hz	
Pulsed Width	3ms – 5ms	
Working temperature	-40°C - 60°C	
Storage temperature	-55°C - 75°C	
Life Time	10000000 times	
Weight	<80g	

Dimension of SLY-1535-2000-A8:



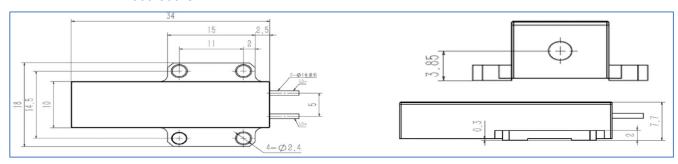


7. C1 Series Er Glass Lasers SLY-1535-500-C1

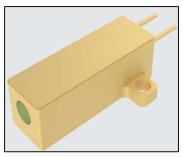


Parameters	SLY-1535-500-C1
Wavelength	1535nm
Pulsed width (FWHM)	4ns - 6ns
Pulsed energy (µJ)	500
Peak Power (kw)	100
Energy Stability	≤5%
Beam-divergence angle	≤12mrad
Working Voltage	2V
Working current (A)	15
Working Frequency	1Hz – 5Hz
Pulsed Width	1ms – 2.5ms
Working temperature	-40°C - 60°C
Storage temperature	-50°C - 70°C
Life Time	10000000 times
Weight	<20g

Dimension of SLY-1535-500-C1:



8. C2 Series Er Glass Lasers SLY-1535-40-C2

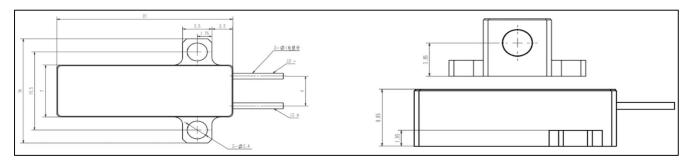


Parameters	SLY-1535-40-C2
Wavelength	1535nm
Pulsed width (FWHM)	3ns - 4ns
Pulsed energy (µJ)	40
Peak Power (kw)	10
Energy Stability	≤5%

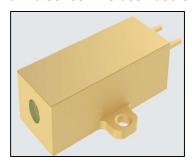


Beam-divergence angle	≤15mrad	
Working Voltage	2V	
Working current (A)	3	
Working Frequency	1000Hz	
Pulsed Width	0.2ms - 0.4ms	
Working temperature	-40°C - 60°C	
Storage temperature	-50°C - 70°C	
Life Time	10000000 times	
Weight	<10g	

Dimension of SLY-1535-40-C2:



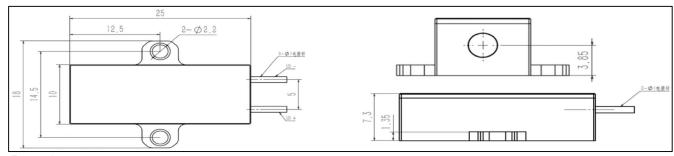
9. C3 Series Er Glass Lasers SLY-1535-xxx-C3



Parameters	SLY-1535-100-C3	SLY-1535-200-C3	SLY-1535-300-C3	SLY-1535-400-C3
Wavelength	1535nm			
Pulsed width (FWHM)	≤12ns			
Pulsed energy (µJ)	100	200	300	400
Peak Power (kw)	25	50	70	80
Energy Stability	≤5%			
Beam-divergence angle	≤0.5mrad			
Working Voltage	2V			
Working current (A)	7	12	12	14
Working Frequency	1Hz - 10Hz			
Pulsed Width	1ms - 2.5ms			
Working temperature	-50°C - 70°C			
Storage temperature	-55°C - 75°C			
Life Time	10000000 times			
Weight	<15g			



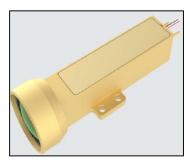
Dimension of SLY-1535-xxx-C3:



Remark:

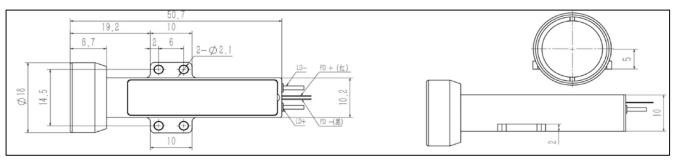
xxx: pulsed energy (µJ)

10. C7 Series Er Glass Lasers SLY-1535-40-C7



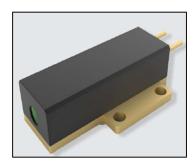
Parameters	SLY-1535-40-C7	
Wavelength	1535nm	
Pulsed width (FWHM)	3ns - 5ns	
Pulsed energy (µJ)	40	
Peak Power (kw)	10	
Energy Stability	≤5%	
Beam-divergence angle	≤0.5mrad	
Working Voltage	2V	
Working current (A)	3	
Working Frequency	1000Hz	
Pulsed Width	0.2ms – 0.4ms	
Working temperature	-40°C - 60°C	
Storage temperature	-50°C - 70°C	
Life Time	10000000 times	
Weight	<30g	

Dimension of SLY-1535-40-C7:



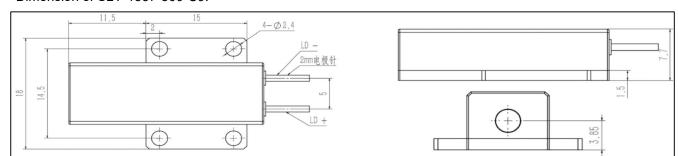


11. C7 Series Er Glass Lasers SLY-1537-500-C9



Parameters	SLY-1537-500-C9	
Wavelength	1537nm	
Pulsed width (FWHM)	4ns - 7ns	
Pulsed energy (µJ)	500	
Peak Power (kw)	10	
Energy Stability	≤5%	
Beam-divergence angle	≤5mrad	
Working Voltage	4V	
Working current (A)	20	
Repeating Frequency	10Hz	
Working temperature	-40°C - 60°C	
Storage temperature	-55°C - 75°C	
Life Time	10000000 times	
Weight	<20g	

Dimension of SLY-1537-500-C9:



NOTE:

- 1. Anti-static measures must be taken during transportation, storage and use.
- 2. Laser diode pins need to be protected by connecting short lines between them.
- 3. Laser window to ensure clean and pollution-free.
- 4. Use constant-current power supply to avoid peaks and surges when working.
- 5. The laser must be installed reliably when working.
- 6. Follow the operating instruction manual.
- 7. For other questions, please contact us.





SED Series Erbium-doped Glass Microchip Lasers

Parts Numbering Schema

Series - Wavelength - Pulse Energy - Pulse Width- Others

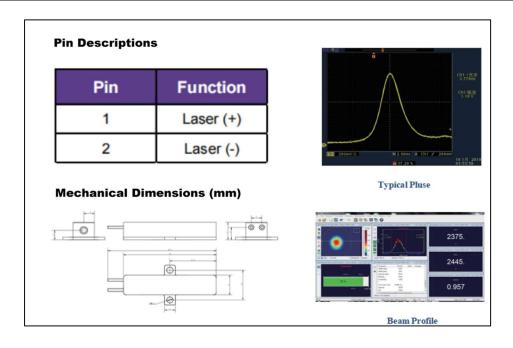
For example: SED-1535nm-100uJ-3.5ns, is a SED Erbium-doped laser with 1535nm wavelength, 120uJ Pulse energy and 3.5ns pulse width.

1. 500 µJ Erbium-doped glass laser, SED-1535nm-500uJ-5ns

The erbium glass laser emits at an eye-safe wavelength of $1.54\mu m$ and offers high beam quality within the atmospheric window. With a pulse energy of $500~\mu J$, it is suitable for eye-safe laser ranging. This laser exhibits low power consumption, high peak power, narrow pulse width, compact size, and does not require temperature control. It has been proven to be a safe, efficient, and stable eye-safe laser solution.



Wavelength	1535nm
Pulse energy (Min/Typ.)	≥500µJ
Pulse width, Typ. (FWHM)	5ns
Pulse repetition rate	1~10Hz
Pulse stability	10%
Spots diameter	0.3mm
Beam divergence angle	10mrad
Spots mode	TEM00
Operating temperature	-45 °C~ +65°C
Storage temperature	-55 °C~ +85°C
Impact	1500G, 0.5ms
Vibration	20~2000 Hz/20G
Life span	>50 million shots
Dimension (mm)	32x8x7
Weight	10g
Voltage	2V
Current	20A
Pulse width	≥2.4ms





2. 2mJ Erbium-doped Glass Laser, SED-1535nm-2mJ-11ns

This laser employs erbium glass as the active medium operating at a wavelength of 1.54 μ m. It offers a high photoelectric conversion efficiency, effectively converting electrical energy into laser power. With excellent optical performance and output stability, it consistently delivers pulse energy of over 2mJ. It is compact, lightweight, and excels in various fields such as scientific research, medical treatment, and industrial processing.



Wavelength	1535nm
Pulse energy (Min/Typ.)	≥2mJ
Pulse width, Typ. (FWHM)	11ns
Pulse repetition rate	5Hz
Pulse stability	±5%
Spots diameter	0.5mm
Beam divergence angle	4mrad
Spots mode	TEM00
Operating temperature	-45 °C~ +65°C
Storage temperature	-55 °C~ +85°C
Impact	1500G, 0.5ms
Vibration	5~2000 Hz/20G
Life span	>50 million shots
Dimension (mm)	60x34x26
Weight	120g
Voltage	5V
Current	65A
Pulse width	≥4ms

